

RQ3E100BNTB Information


For Reference Only

Part Number [RQ3E100BNTB](#)
Manufacturer Rohm Semiconductor
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 30V 10A HSMT8
Package 8-PowerVDFN
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


RQ3E100BNTB Specifications

Manufacturer Part Number	RQ3E100BNTB
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	8-PowerVDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	10A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1100pF @ 15V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2W (Ta)
Rds On (Max) @ Id, Vgs	10.4 mOhm @ 10A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-HSMT (3.2x3)
Package / Case	8-PowerVDFN

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RQ3E100BNTB Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RQ3E100BNTB Payment Methods



RQ3E100BNTB Shipping Methods



If you have any question about RQ3E100BNTB, please do not hesitate to contact us!

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